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# FDD9407-F085

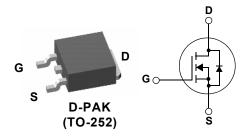
# N-Channel Power Trench® MOSFET **40V**, **100A**, **2.0m**Ω

#### **Features**

- Typ  $r_{DS(on)}$  = 1.6m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 80A
- Typ  $Q_{g(tot)}$  = 86nC at  $V_{GS}$  = 10V,  $I_D$  = 80A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

#### **Applications**

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems





### **MOSFET Maximum Ratings** T<sub>J</sub> = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
$V_{DSS}$	Drain to Source Voltage		40	V
$V_{GS}$	Gate to Source Voltage		±20	V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> = 25°C	100	А
ID	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure4	A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	171	mJ
D	Power Dissipation		227	W
$P_D$	Derate above 25°C		1.52	W/°C
$T_J$ , $T_{STG}$	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.66	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9407	FDD9407-F085	D-PAK(TO-252)	13"	12mm	2500 units

- 1: Current is limited by bondwire configuration.
- 1. Cutrent is inflited by borlowing configuration. 2: Starting  $T_J = 25^{\circ}C$ , L = 0.08mH,  $I_{AS} = 64$ A,  $V_{DD} = 40$ V during inductor charging and  $V_{DD} = 0$ V during time in avalanche 3:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Units

Max

Тур

<b>Electrical Characteristics</b>	T <sub>1</sub> = 25°C unless otherwise noted
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**Parameter** 

Off Characteristics								
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V$	V <sub>GS</sub> = 0V	40	-	-	٧	
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>DS</sub> =40V,	$T_{J} = 25^{\circ}C$	-	-	1	μΑ	
		$V_{GS} = 0V$	$T_J = 175^{\circ}C(Note 4)$	-	-	1	mA	
1	Cate to Source Leakage Current	\/ = +20\/				+100	nΔ	

Test Conditions

Min

## **On Characteristics**

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		2.0	3.1	4.0	V
r <sub>DS(on)</sub> Drain to Source On Resistance	Drain to Source On Registance	I <sub>D</sub> = 80A,	$T_{J} = 25^{\circ}C$	-	1.6	2	$m\Omega$
	V <sub>GS</sub> = 10V	$T_J = 175^{\circ}C(Note 4)$	-	2.64	3.22	$m\Omega$	

# **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	-V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, -f = 1MHz		-	6390	-	pF
C <sub>oss</sub>	Output Capacitance			-	1580	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	95	-	pF
$R_g$	Gate Resistance	f = 1MHz		-	2.3	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V	V <sub>DD</sub> = 32V	-	86	112	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	I <sub>D</sub> = 80A	-	12	15.6	nC
$Q_{gs}$	Gate to Source Gate Charge		_	-	30	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge			-	15	-	nC

# **Switching Characteristics**

t <sub>on</sub>	Turn-On Time	$V_{DD}$ = 20V, $I_{D}$ = 80A, $V_{GS}$ = 10V, $R_{GEN}$ = $6\Omega$	-	-	120	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	27	-	ns
t <sub>r</sub>	Rise Time		-	48	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	42	-	ns
t <sub>f</sub>	Fall Time		-	18	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	97	ns

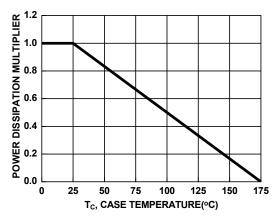
### **Drain-Source Diode Characteristics**

V <sub>SD</sub>	I SOURCE TO LITZIN LILIONE VOITZOE	I <sub>SD</sub> = 80A, V <sub>GS</sub> = 0V	-	-	1.25	V
		$I_{SD} = 40A, V_{GS} = 0V$	-	-	1.2	V
T <sub>rr</sub>	Reverse Recovery Time	$I_F = 80A$ , $dI_{SD}/dt = 100A/\mu s$ ,	-	58	88	ns
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> =32V	-	83	143	nC

#### Notes:

<sup>4:</sup> The maximum value is specified by design at TJ = 175°C. Product is not tested to this condition in production.

# **Typical Characteristics**



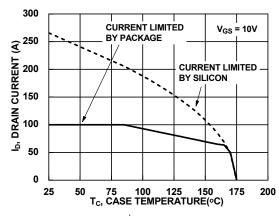


Figure 1. Normalized Power Dissipation vs Case Temperature

Figure 2. Maximum Continuous Drain Current vs
Case Temperature

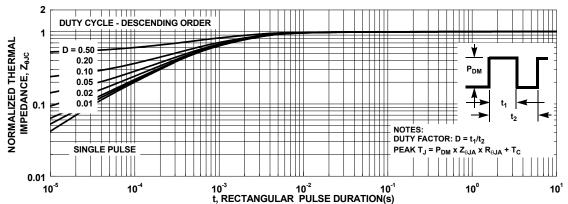


Figure 3. Normalized Maximum Transient Thermal Impedance

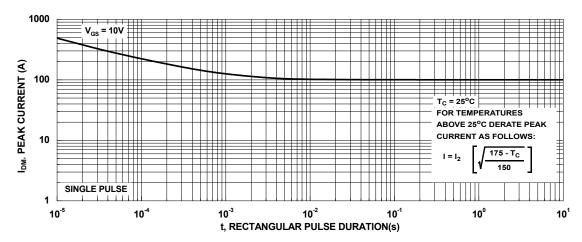


Figure 4. Peak Current Capability

# **Typical Characteristics**

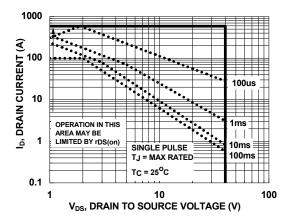


Figure 5. Forward Bias Safe Operating Area

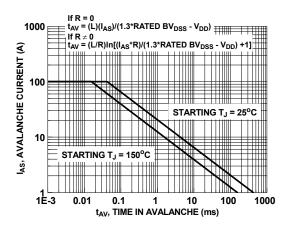


Figure 6. Unclamped Inductive Switching Capability

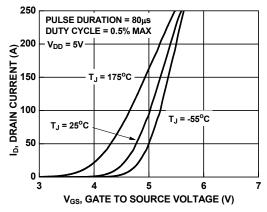


Figure 7. Transfer Characteristics

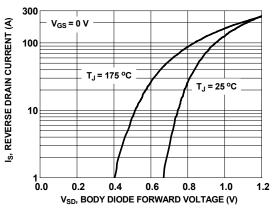


Figure 8. Forward Diode Characteristics

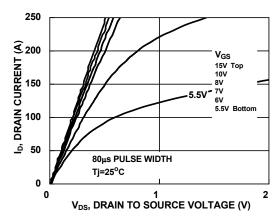


Figure 9. Saturation Characteristics

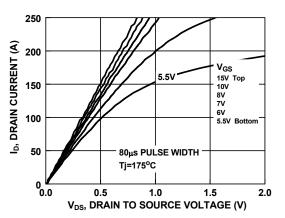


Figure 10. Saturation Characteristics

# **Typical Characteristics**

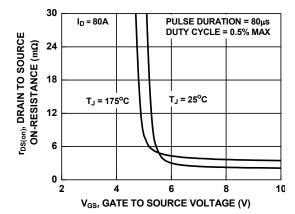


Figure 11. Rdson vs Gate Voltage

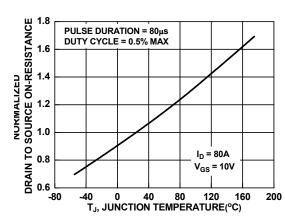


Figure 12. Normalized Rdson vs Junction Temperature

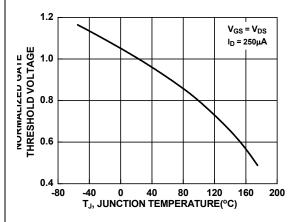


Figure 13. Normalized Gate Threshold Voltage vs Temperature

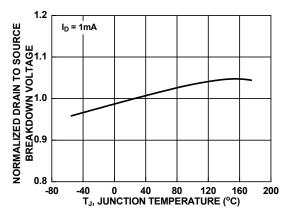


Figure 14. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

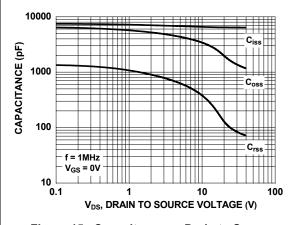


Figure 15. Capacitance vs Drain to Source Voltage

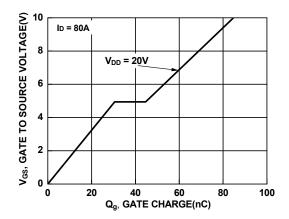


Figure 16. Gate Charge vs Gate to Source Voltage

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